# S3AB - S3MB

Taiwan Semiconductor

# 3A, 50V - 1000V Surface Mount Rectifier

### FEATURES

TAIWAN

Glass passivated chip junction

SEMICONDUCTOR

- Ideal for automated placement
- Low forward voltage drop
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

## APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

## **MECHANICAL DATA**

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.09 g (approximately)

| KEY PARAMETERS     |                |      |  |  |  |
|--------------------|----------------|------|--|--|--|
| PARAMETER          | VALUE          | UNIT |  |  |  |
| I <sub>F(AV)</sub> | 3              | А    |  |  |  |
| V <sub>RRM</sub>   | 50 - 1000      | V    |  |  |  |
| I <sub>FSM</sub>   | 80             | А    |  |  |  |
| T <sub>J MAX</sub> | 150 °C         |      |  |  |  |
| Package            | DO-214AA (SMB) |      |  |  |  |
| Configuration      | Single Die     |      |  |  |  |





DO-214AA (SMB)

| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)                             |                     |                               |      |      |      |      |      |      |      |
|---|---------------------|-------------------------------|------|------|------|------|------|------|------|
| PARAMETER   | SYMBOL              | S3AB                          | S3BB | S3DB | S3GB | S3JB | S3KB | S3MB | UNIT |
| Marking code on the device  |                     | S3AB                          | S3BB | S3DB | S3GB | S3JB | S3KB | S3MB |      |
| Repetitive peak reverse voltage   | V <sub>RRM</sub>    | 50                            | 100  | 200  | 400  | 600  | 800  | 1000 | V    |
| Reverse voltage, total rms value  | V <sub>R(RMS)</sub> | 35                            | 70   | 140  | 280  | 420  | 560  | 700  | V    |
| Maximum DC blocking voltage   | V <sub>DC</sub>     | 50                            | 100  | 200  | 400  | 600  | 800  | 1000 | V    |
| Forward current   | I <sub>F(AV)</sub>  |                               |      |      | 3    |      |      |      | Α    |
| Surge peak forward current, 8.3 ms<br>single half sine-wave superimposed<br>on rated load per diode | I <sub>FSM</sub>    | 80                            |      |      | A    |      |      |      |      |
| Junction temperature  | TJ                  | J - 55 to +150                |      |      | °C   |      |      |      |      |
| Storage temperature   | T <sub>STG</sub>    | T <sub>STG</sub> - 55 to +150 |      |      | °C   |      |      |      |      |



| THERMAL PERFORMANCE                 |                 |       |      |
|-------------------------------------|-----------------|-------|------|
| PARAMETER                           | SYMBOL          | LIMIT | UNIT |
| Junction-to-lead thermal resistance | $R_{\Theta JL}$ | 10    | °C/W |

| <b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted) |   |                 |      |      |      |  |
|--|---|-----------------|------|------|------|--|
| PARAMETER  | CONDITIONS  | SYMBOL          | ТҮР  | MAX  | UNIT |  |
| Forward voltage per diode <sup>(1)</sup>                                       | $I_F = 3A, T_J = 25^{\circ}C$   | V <sub>F</sub>  | -    | 1.15 | V    |  |
|  | $T_J = 25^{\circ}C$   |                 | -    | 10   | μA   |  |
| Reverse current @ rated $V_R$ per diode <sup>(2)</sup>                         | T <sub>J</sub> = 125°C  | I <sub>R</sub>  | -    | 250  | μA   |  |
| Junction capacitance   | 1 MHz, V <sub>R</sub> =4.0V   | CJ              | 40   | -    | pF   |  |
| Reverse recovery time  | I <sub>F</sub> =0.5A , I <sub>R</sub> =1.0A<br>I <sub>RR</sub> =0.25A | +               | 1500 | -    | 20   |  |
| Reverse recovery line  | I <sub>RR</sub> =0.25A  | t <sub>rr</sub> |      |      | ns   |  |

#### Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

| ORDERING INFORMATION |                    |                 |                           |         |                          |  |  |
|----------------------|--------------------|-----------------|---------------------------|---------|--------------------------|--|--|
| PART NO.             | PART NO.<br>SUFFIX | PACKING<br>CODE | PACKING CODE<br>SUFFIX(*) | PACKAGE | PACKING                  |  |  |
|                      | н                  | R5              | R5                        |         | 850 / 7" Plastic reel    |  |  |
| S3xB                 |                    | R4              | G                         | SMB     | 3,000 / 13" Paper reel   |  |  |
| (Note 1)             |                    | M4              |                           | SMB     | 3,000 / 13" Plastic reel |  |  |

Note:

1. "x" defines voltage from 50V (S3AB) to 1000V (S3MB)

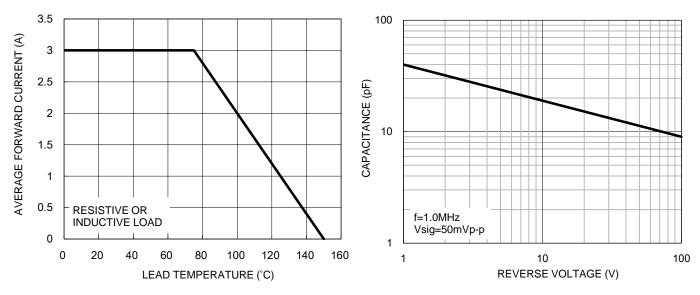
\*: Optional available

| EXAMPLE P/N |          |                    |                 |                        |                                      |
|-------------|----------|--------------------|-----------------|------------------------|--------------------------------------|
| EXAMPLE P/N | PART NO. | PART NO.<br>SUFFIX | PACKING<br>Code | PACKING CODE<br>SUFFIX | DESCRIPTION                          |
| S3ABHR5G    | S3AB     | Н                  | R5              | G                      | AEC-Q101 qualified<br>Green compound |

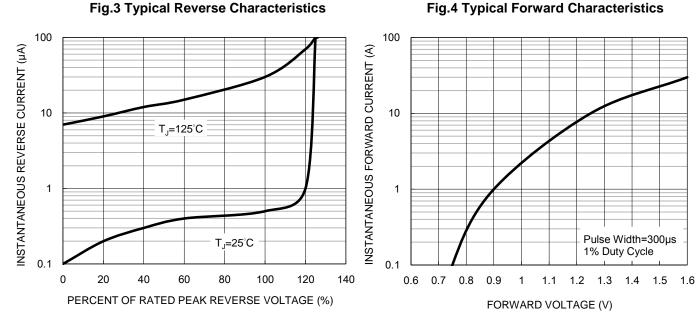


## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)



#### Fig.1 Forward Current Derating Curve

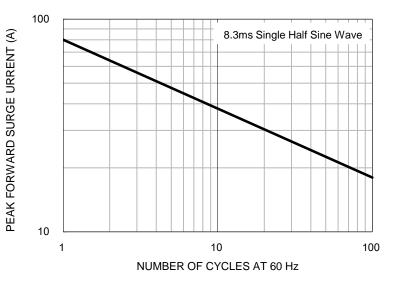


ent Derating Curve

#### Fig.2 Typical Junction Capacitance

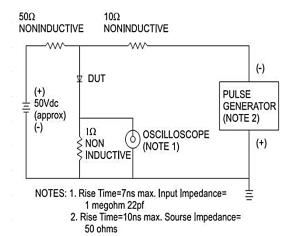


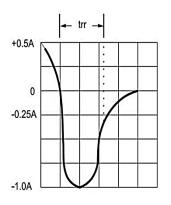
Taiwan Semiconductor

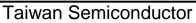


#### Fig.5 Maximum Non-repetitive Forward Surge Current

#### Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram



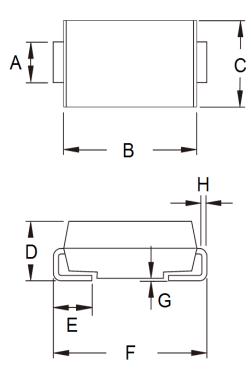






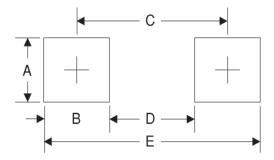
## **PACKAGE OUTLINE DIMENSIONS**

DO-214AA (SMB)



| DIM.   | Unit (mm) |      | Unit (inch) |       |  |
|--------|-----------|------|-------------|-------|--|
| Dilvi. | Min       | Max  | Min         | Max   |  |
| А      | 1.95      | 2.20 | 0.077       | 0.087 |  |
| В      | 4.05      | 4.60 | 0.159       | 0.181 |  |
| С      | 3.30      | 3.95 | 0.130       | 0.156 |  |
| D      | 1.95      | 2.65 | 0.077       | 0.104 |  |
| Е      | 0.75      | 1.60 | 0.030       | 0.063 |  |
| F      | 5.10      | 5.60 | 0.201       | 0.220 |  |
| G      | 0.05      | 0.20 | 0.002       | 0.008 |  |
| Н      | 0.15      | 0.31 | 0.006       | 0.012 |  |

## SUGGESTED PAD LAYOUT



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| А      | 2.3       | 0.091       |
| В      | 2.5       | 0.098       |
| С      | 4.3       | 0.169       |
| D      | 1.8       | 0.071       |
| E      | 6.8       | 0.268       |

## **MARKING DIAGRAM**



P/N

= Marking Code = Green Compound G

YW = Date Code

F = Factory Code



Taiwan Semiconductor

# Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 CRS04(T5L,TEMQ)
 ACGRA4007-HF

 ACGRB207-HF
 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6359
 NTE6002
 NTE6023
 NTE6039
 NTE6077

 85HFR60
 40HFR60
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K
 VS 

 12FL100S10
 ACGRA4001-HF
 D1821SH45T PR
 D1251S45T
 NTE5990
 NTE6358
 NTE6162
 NTE5850